

Octal-Bus Transceiver/Registers, 3-State

B3 DATA CD54/74AC/ACT651 - Inverting
B5 PORT CD54/74AC/ACT652 - Non-Inverting

Type Features:

- Buffered inputs
- Typical propagation delay: 5.3 ns @ V_{CC} = 5 V, T_A = 25° C, C_L = 50 pF

FUNCTIONAL DIAGRAM

92CS-42677

The RCA CD54/74AC651 and CD54/74AC652 and the CD54/74ACT651 and CD54/74ACT652 3-state, octal-bus transceiver/registers use the RCA ADVANCED CMOS technology. The CD54/74AC651 and CD54/74ACT651 have inverting outputs. The CD54/74AC652 and CD54/74ACT652 have non-inverting outputs. These devices consist of bus transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Output Enables OEAB and OEBA are provided to control the transceiver functions. SAB and SBA control pins are provided to select whether real-time or stored data is transferred. The circuitry used for select control will eliminate the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. A LOW input level selects real-time data, and a HIGH selects stored data. The following examples demonstrate the four fundamental busmanagement functions that can be performed with the octal-bus transceivers and registers.

Data on the A or B data bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock pins (CAB or CBA) regardless of the select or enable control pins. When SAB and SBA are in the real-time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and $\overline{\text{OE}}_{\text{BA}}$. In this configuration, each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines will remain at its last state.

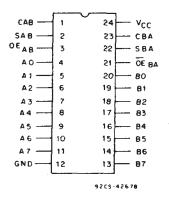
The CD74AC/ACT651 and CD74AC/ACT652 are supplied in 24-lead dual-in-line narrow-body plastic packages (EN suffix) and in 24-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC/ACT651 and CD54AC/ACT652, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

Family Features:

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST*/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply
- ± 24-mA output drive current
 - Fanout to 15 FAST* ICs
 - Drives 50-ohm transmission lines

^{*}FAST is a Registered Trademark of Fairchild Semiconductor Corp.



TERMINAL ASSIGNMENT

FUNCTION TABLE

		INP	UTS			DAT	A I/O	OPERATION (OR FUNCTION	
OEAB	OEBA	CAB	CBA	SAB	SBA	A0 THRU A7	B0 THRU B7	651	652	
L	Н	HorL	H or L	Х	X	Input	lanut	Isolation *	Isolation*	
L	Н	_/_		Х	X	Input	Input	Store A and B Data	Store A and B Data	
X	Н		HorL	, х	X	Input	Unspecified [†]	Store A, Hold B	Store A, Hold B	
Н	<u> H</u>			x‡	X	Input	Output	Store A in both registers	Store A in both registers	
L	X	HorL		×	X	Unspecified†	Input	Hold A, Store B	Hold, A Store B	
L	L			X	X‡	Output	Input	Store B in both registers	Store B in both registers	
L	L	Х	Х	X	L	0		Real-Time B Data to A Bus	Real-Time B Data to A Bus	
L	L	Х	HorL	X	Н	Output	Input	Stored B Data to A Bus	Stored B Data to A Bus	
Н	Н	X	Х	L	X			Real-Time A Data to B Bus	Real-Time A Data to B Bus	
Н	Н	HorL	X	Н	X	Input	Output	Stored A Data to B Bus	Stored A Data to B Bus	
н	-	HorL	Harl	н	н	0.4		Stored A Data to B Bus and	Stored A Data to B Bus	
		HOLL	n or L	П	П	Output	Output	Stored B Data to A bus	Stored B Data to A Bus	

^{*} To prevent excess currents in the High-Z (isolation) modes, all I/O terminals should be terminated with $10k\Omega$ to $1M\Omega$ resistors.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE (V _∞)0.5 to 6 V	J
DC INPUT DIODE CURRENT, I_{ik} (for $V_i < -0.5 \text{ V}$ or $V_i > V_{CC} + 0.5 \text{ V}$)	Δ
DC OUTPUT DIODE CURRENT, I_{OK} (for $V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$)	Δ
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, I _o (for $V_0 > -0.5 \text{ V}$ or $V_0 < V_{cc} + 0.5 \text{ V}$)	Δ
DC V _{CC} or GROUND CURRENT (I _{CC} or I _{GND})	*
POWER DISSIPATION PER PACKAGE (Po):	
For T _A = -55 to +100°C (PACKAGE TYPE E)	٧
For T _A = +100 to +125°C (PACKAGE TYPE E)	V
For T _A = -55 to +70°C (PACKAGE TYPE M)	V
For T _A = +70 to +125°C (PACKAGE TYPE M) Derate Linearly at 6 mW/°C to 70 mW	V
OPERATING-TEMPERATURE RANGE (T _a)55 to ±125°C)
STORAGE TEMPERATURE (T _{stg})65 to ±150°C	5
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm) from case for 10 s maximum $+265^{\circ}$ C)
Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contacting lead tips only+300°C)
*For up to 4 outputs per device; add + 25 mA for each additional output	

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTICS	LIA	LINUTO		
CHARACTERISTICS	MIN.	MAX.	UNITS	
Supply-Voltage Range, Vcc*:				
(For T _A = Full Package-Temperature Range)		İ		
AC Types	1.5	5.5	V	
ACT Types	4.5	5.5	V	
DC Input or Output Voltage, V _I , V _O	0	Vcc	V	
Operating Temperature, T _A	-55	+125	°C	
Input Rise and Fall Slew Rate, dt/dv		† 		
at 1.5 V to 3 V (AC Types)	0	50	ns/V	
at 3.6 V to 5.5 V (AC Types)	0	20	ns/V	
at 4.5 V to 5.5 V (ACT Types)	0	10	ns/V	

^{*}Unless otherwise specified, all voltages are referenced to ground.

[†] The data output functions may be enabled or disabled by various signals at the OE_{AB} or OE_{BA} inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.

 ^{\$}Select control = L: clocks can occur simultaneously.
 \$Select control = H: clocks must be staggered in order to load both registers.

STATIC ELECTRICAL CHARACTERISTICS: AC Series

. •					AMBIEN	TEMPE	RATURE	(T _A) - °	С .		
CHARACTERIST	ICS	TEST CO	NDITIONS	V _{cc}	+:	25	-40't	o +85	-55 to	+125	UNITS
		V, (V).	l _o (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V _{IH}			1.5 3 5.5	1.2 2.1 3.85		1.2 2.1 3.85		1.2 2.1 3.85		v
Low-Level Input Voltage	Vil			1.5 3 5.5		0.3 0.9 1.65	_	0.3 0.9 1.65	=	0.3 0.9 1.65	V
High-Level Output			-0.05	1.5	1.4		1.4	_	1.4		
Voltage	V _{OH}	VIH	-0.05	3	2.9	<u> </u>	2.9	_	2.9]
,		or	-0.05	4.5	4.4	_	4.4	_	4.4		
		V _{iL}	-4	3	2.58		2.48	_	2.4) v
			-24	4.5	3.94	_	3.8	_	3.7		
		#, * }	-75	5.5	_		3.85]
		"' (-50	5.5		_			3.85		<u></u>
Low-Level Output			0.05	1.5		0.1		0.1		0.1	
Voltage	V_{OL}	V _{IH}	0.05	3		0.1		0.1		0.1	
		or	0.05	4.5		0.1		0.1		0.1	
		VıL	12	3		0.36		0.44		0.5) v
	!		24	4.5		0.36		0.44		0.5	
		#, * {	75	5.5				1.65			
		(50	5.5	_		<u> </u>			1.65	
Input Leakage Current	l ₁	V _{cc} or GND		5.5	_	±0.1		±1	_	±1	μΑ
3-State Leakage Current	łoz	VIH or VIL Vo= Vcc or GND		5.5		±0.5		±5		±10	μΑ
Quiescent Supply Current, MSI	Icc	V _{cc} or GND	0	5.5	_	8		80		160	μΑ

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

^{*}Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

					AMBIEN	T TEMPE	RATURE	(T _A) - °	С		
CHARACTERISTI	CS	TEST COM	NDITIONS	V _{cc}	+	25	-40 t	o +85	-55 to	+125	UNITS
		V, (V)	l _o (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V _{IH}			4.5 to 5.5	2	_	2	· —	2		V
Low-Level Input Voltage	ViL		•	4.5 to 5.5		0.8		0.8	_	0.8	v
High-Level Output		V _{IH}	-0.05	4.5	4.4	_	4.4		4.4	<u> </u>	
Voltage	V _{OH}	or V _{IL}	-24	4.5	3.94		3.8		3.7]
		#, * {	-75	5.5			3.85	-		[V
		"' ℓ	-50	5.5				_	3.85	_	
Low-Level Output		V _{IH}	0.05	4.5	–	0.1	-	0.1	-	0.1	
Voltage	Vol	or V _{IL}	24	4.5	<u> </u>	0.36	_	0.44		0.5	1 v
		#, * {	75	5.5	_	_	_	1.65	_	_	1
		" '	50	5.5	_				_	1.65	1
Input Leakage Current	ŀı	V _{cc} or GND		5.5	_	±0.1	_	±1	_	±1	μΑ
3-State Leakage Current	loz	VIH or VIL Vo= Vcc or GND		5.5	_	±0.5	_	±5	_	±10	μΑ
Quiescent Supply Current, MSI	lcc	V _{cc} or GND	0	5.5	_	8	_	80	_	160	μΑ
Additional Quiescent S Current per Input Pi TTL Inputs High 1 Unit Load		V _{cc} -2.1		4.5 to 5.5		2.4	_	2.8		3	mA

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

ACT INPUT LOADING TABLE

INPUT	UNIT LOAD*
CAB, CBA	1.25
SAB, SBA	1.2
OE _{AB}	0.67
OE _{BA}	1.17
An, Bn	0.4

*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

PREREQUISITE FOR SWITCHING: AC Series

			AMBI	ENT TEMPE	RATURE (1	'Y) - °C		
CHARACTERISTICS	SYMBOL	V _{cc} (V)	-40 1	o +85	-55 to	UNITS		
			MIN.	MAX.	MIN.	MAX.	1	
Max. Frequency	f _{max}	1.5 3.3* 5†	11 101 143		10 89 125		MHz	
Setup Time Data to Clock	tsu	1.5 3.3 5	27 3.1 2.2	=	31 3.5 2.5		ns	
Hold Time Data to Clock	t _H	1.5 3.3 5	2 2 2	=	2 2 2		ns	
Clock Pulse Data to Clock	tw	1.5 3.3 5	44 4.9 3.5	=	50 5.6 4		ns	

*3.3 V: min. is @ 3 V †5 V; min. is @ 4.5 V

SWITCHING CHARACTERISTICS: AC Series; t., t. = 3 ns, CL = 50 pF

			AMBI	ENT TEMPE	RATURE (Γ _Λ) - °C	
CHARACTERISTICS	SYMBOL	V _{cc}	-40	to +85	-55 t	o +125	UNITS
O MAIN TERMOTION	01002	(V)	MIN.	MAX.	MIN.	MAX.	7
Propagation Delays: Store A Data to B Bus Store B Data to A Bus 652 Store A Data to B Bus Store B Data to A Bus 651	tры tры tры tры	1.5 3.3* 5† 1.5 3.3 5	4.8 3.5 4.8 3.5	154 17.1 12.3 154 17.1 12.3	4.7 3.4 - 4.7 3.4	169 18.9 13.5 169 18.9 13.5	ns
A Data to B Bus B Data to A Bus 652	t _{PLH} t _{PHL}	1.5 3.3 5	4 2.8	125 14 10	3.9 2.8	138 15.4 11	ns
A Data to B Bus B Data to A Bus 651	telh tehl	1.5 3.3 5	- 4 2.8	125 14 10	3.9 2.8	138 15.4 11	ns
Select to Data 652	telm tem	1.5 3.3 5	4.3 3.1	136 15.3 10.9	4.2 3	150 16.8 12	ns
Select to Data 651	tplH tpHL	1.5 3.3 5	4.3 3.1	136 15.3 10.9	4.2 3	150 16.8 12	ns
3-State Enabling/ Disabling Time Bus to Output or Register to Output	tezl tezh telz tenz	1.5 3.3 5	5.2 3.5	154 18.4 12.3	5.1 3.4	169 20.2 13.5	ns
Power Dissipation Capacitance	CPD§	_	150	Тур.	150	Тур.	pF
Min. (Valley) During Switching of Other Outputs (Output Under Test Not Switching)	V _{OHV} V _{OHV} See Fig. 1	5	4 Typ. @ 25°C				V
Max. (Peak) During Switching of Other Outputs (Output Under Test Not Switching)	Vol.P See Fig. 1	5	1 Typ. @ 25°C				٧
Input Capacitance	C ₁			10		10	pF
3-State Output Capacitance	Co	_		15		15	pF

*3 3 V: min, is @ 3.6 V max. is @ 3 V

†5 V: min. is @ 5.5 V max. is @ 4.5 V C_{PD} is used to determine the dynamic power consumption, per package. $P_D = V_{CC}^2 C_{PD} f_i + \Sigma (V_{CC}^2 C_L f_o)$ where $f_i =$ input frequency

f_o = output frequency C_L = output load capacitance

Vcc - supply voltage.

PREREQUISITE FOR SWITCHING: ACT Series

		•	AMBI				
CHARACTERISTICS	SYMBOL	V _{cc} (V)	-40 t	o +85	-55 to	UNITS	
		(*/	MIN.	MAX.	MIN.	MAX.	
Max. Frequency	f _{max}	5*	125	_	110	_	MHz
Setup Time Data to Clock	tsu	5	2.2		2.5	_	ns
Hold Time Data to Clock	t _H	5	2	-	2	_	ns
Clock Pulse Width	tw	5	3.9	_	4.5	_	ns

^{*5} V: min. is @ 4.5 V

SWITCHING CHARACTERISTICS: ACT Series; $t_{\rm r},\,t_{\rm f}$ = 3 ns, $C_{\rm L}$ = 50 pF

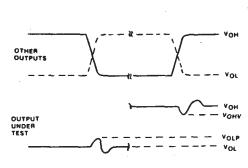
			AMBI	ENT TEMP	ERATURE (T _A) - °C		
CHARACTERISTICS	SYMBOL	V _{cc}	-40	to +85	-55 t	o +125	UNITS	
· · · · · · · · · · · · · · · · · · ·		(V)	MIN.	MAX.	MIN.	MAX.		
Propagation Delays: Store A Data to B Bus Store B Data to A Bus 652	t _{PLH} t _{PHL}	5⁺	4	14.1	3.9	15.5	ns	
Store A Data to B Bus Store B Data to A Bus 651	t _{PLH} t _{PHL}	5	4	14.1	3.9	15.5	ns	
A Data to B Bus B Data to A Bus 652	t _{PLH} t _{PHL}	5	3.2	11.4	3.1	12.5	ns	
Ā Data to B Bus B Data to A Bus 651	t _{PLH} t _{PHL}	5	3.2	11.4	3.1	12.5	ns	
Select to Data 652	t _{PLH} t _{PHL}	5	3.7	13.2	3.6	14.5	ns	
Select to Data 651	t _{PEH} t _{PHL}	5	4	14.1	3.9	15.5	ns	
3-State Enabling/ Disabling Time Bus to Output or Register to Output	tezi. tezh teiz tenz	5	4	14.1	3.9	15.5	ns	
Power Dissipation Capacitance	CPO§	_	150	Тур.	150	Тур.	pF	
Min. (Valley) During Switching of Other Outputs (Output Under Test Not Switching)	V _{OH} V _{OHV} See Fig. 1	5			9. 150 Typ. 4 Typ. @ 25°C			
Max. (Peak) During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} V _{OLP} See Fig. 1	5	1 Typ. @ 25°C				٧	
Input Capacitance	Cı	-		10	_	10	ρF	
3-State Output Capacitance	Со	_		15	_	15	ρF	

^{*5} V: min. is @ 5.5 V max. is @ 4.5 V

§C_{PD} is used to determine the dynamic power consumption, per package. $P_D = V_{CC}^2 C_{PD} f_i + \sum V_{CC}^2 C_L f_0 + V_{CC} \Delta I_{CC}$ where $f_i = input frequency$

fo = output frequency

C_L = output load capacitance V_{cc} = supply voltage.



- 1. VOHY AND VOLP ARE MEASURED WITH RESPECT TO A GROUND REFERENCE NEAR THE OUTPUT UNDER TEST.

 2. INPUT PULSES HAVE THE FOLLOWING CHARACTERISTICS: PRR © 1 MHZ, \$\frac{1}{2}\$ on \$\frac{1}{2}\$ of \$\scrt{2}\$ of \$\scr
- IC SHOULD BE SOLDERED INTO TEST BOARD AND BYPASSED WITH 0.1 JF CAPACITOR. SCOPE AND PROBES REQUIRE 700-MHz BANDWIDTH.

9205-42406

Fig. 1 - Simultaneous switching transient waveforms.

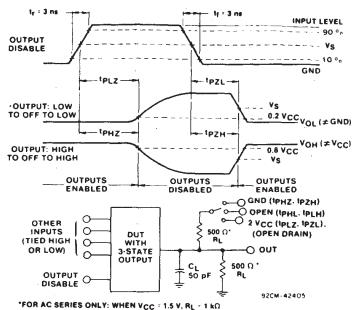


Fig. 2 - Three-state propagation delay waveforms and test circuit.

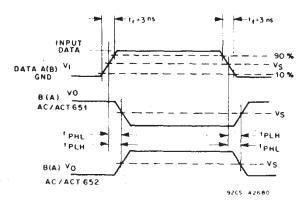


Fig. 3 - Propagation delay times.

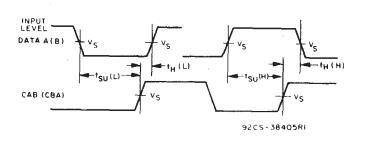


Fig. 4 - Data setup and hold times.

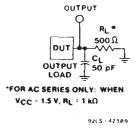


Fig. 5 - Test circuit.

	CD54/74AC	CD54/74ACT
Input Level	Vcc	3 V
Input Switching Voltage, Vs	0.5 V _{cc}	1.5 V
Output Switching Voltage, Vs	0.5 V _{cc}	0.5 V _{cc}

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74AC652M96	ACTIVE	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC652M	Samples
CD74ACT652M96	ACTIVE	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT652M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC652M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74ACT652M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74AC652M96	SOIC	DW	24	2000	350.0	350.0	43.0
CD74ACT652M96	SOIC	DW	24	2000	350.0	350.0	43.0

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